

#### **F80UP30DB**



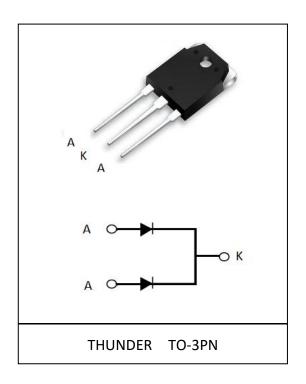
## Thunder High Power Products

# FRED Ultrafast Soft Recovery Diode, 80A

#### **Features:**

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I<sub>R</sub> value
- High surge capacity
- Epitaxial chip construction

Product Summary		
VR	300 V	
lf(AV)	2*40A	
trr	26 ns	



# **Description/Applications**

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

## **Absolute Maximum Ratings**

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		300	V
Continuous forward current	lf(AV)	Tc =110°C	80	
Single pulse forward current	İfsm	Tc =25°C	640	Α
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	250	
Operating junction	Tj		175	°C
Storage temperatures	Tstg		-55 to +175	°C

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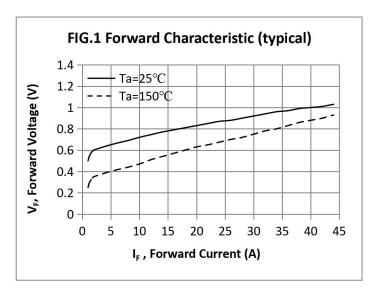
# Electrical characteristics (Ta=25°C unless otherwise specified)

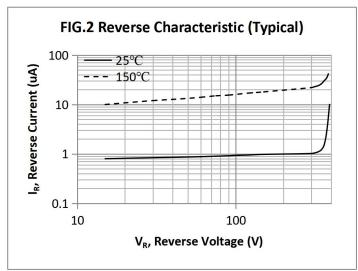
Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units
Breakdown voltage	VBR,	IR=100μΑ	300			
Blocking voltage	$V_R$	IR-100PA	300			
Forward voltage (Per Diode)		IF=40 A		1.0	1.20	V
	VF	IF=40 A, Tj =125°C		0.90	1.00	
Reverse leakage current(Per Diode)	Vr= Vrrm			10		
	Tj=150°C, Vr=300V			100	μ <b>Α</b>	
Reverse recovery time(Per Diode)	trr	I <sub>F</sub> =0.5A, I <sub>R</sub> =1A, I <sub>RR</sub> =0.25A		35	40	nc
	trr	I <sub>F</sub> =1A,V <sub>R</sub> =30V, di/ <i>dt</i> =200A/us		26	35	ns

### **Thermal characteristics**

Paramter	Symbol	Тур	Units
Junction-to-Case	$R_{ heta JC}$	0.7	°C/W

# **Electrical performance (typical)**



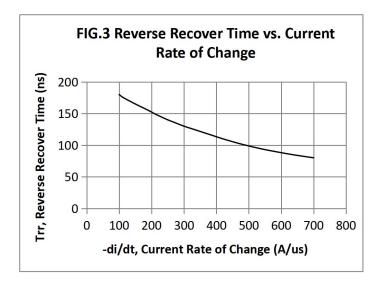


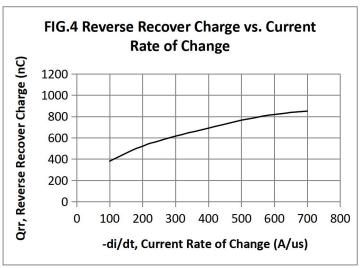
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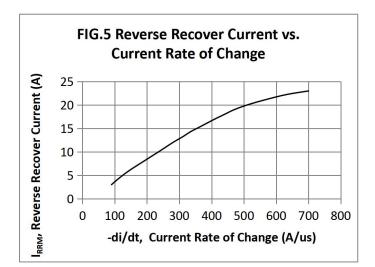


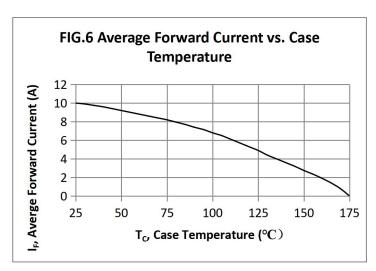


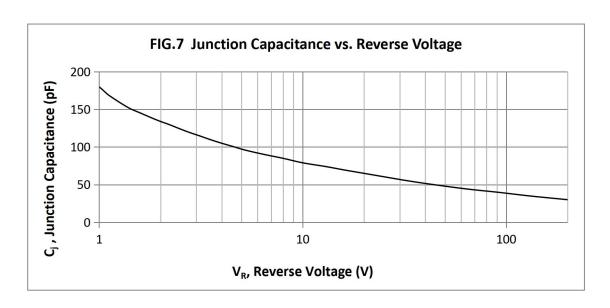












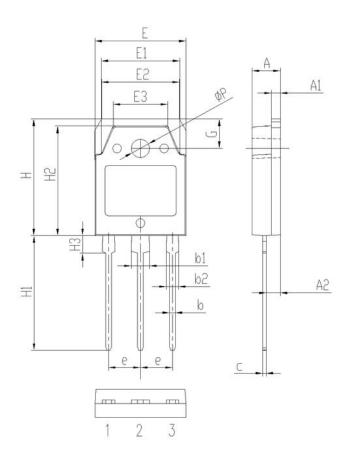
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## **Package Information**

#### **TO-3PN PACKAGE**



Symbol	Dimensions(millimeters)		
Symbol	Min.	Max.	
Α	4.60	5.00	
A1	1.30	1.70	
A2	2.20	2.60	
b	0.80	1.20	
b1	2.90	3.30	
b2	1.90	2.30	
С	0.40	0.80	
е	5.25	5.65	
Е	15.3	15.7	
E1	13.2	13.6	
E2	13.1	13.5	
E3	9.10	9.50	
Н	19.7	20.1	
H1	19.1	20.1	
H2	18.3	18.7	
H3	2.80	3.20	
G	4.80	5.20	
ΦР	3.00	3.40	

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